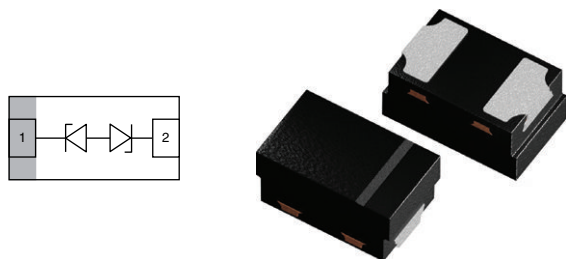




## Single-Line Bidirectional ESD-Protection Diode in DFN1006-2B



## MARKING (example only)



Bar = pin 1 marking

X = date code

YY = type code (see table below)

## FEATURES

- Compact DFN1006-2B package
- Low package height < 0.5 mm
- 1-line bidirectional ESD-protection
- AEC-Q101 qualified available
- Working range  $\pm 14$  V;  $\pm 28$  V
- ESD immunity acc. IEC 61000-4-2  
 $\pm 15$  kV to  $\pm 30$  kV contact discharge  
 $\pm 15$  kV to  $\pm 30$  kV air discharge
- Lead plating: Sn (e3)  
- Soldering can be checked by standard vision inspection  
- AOI = Automated Optical Inspection
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

AUTOMOTIVE  
GRADE  
AvailableRoHS  
COMPLIANT  
HALOGEN  
FREE  
GREEN  
(5-2008)

## LINKS TO ADDITIONAL RESOURCES



3D Models

SPICE

Models

Application  
Notes

## Soldering Recommendations for DFN Packages:

please see Application Note: [www.vishay.com/doc?86198](http://www.vishay.com/doc?86198)

## ORDERING INFORMATION

PART NUMBER (EXAMPLE)	AEC-Q101 QUALIFIED	ENVIRONMENTAL AND QUALITY CODE			ORDERING CODE (EXAMPLE)
		RoHS COMPLIANT + LEAD (Pb)-FREE TERMINATIONS	TIN PLATED	10K PER 7" REEL (8 mm TAPE)	
		GREEN		MOQ = 10K/BOX	
VMMBZ16C1DD1	-	G	3	-08	VMMBZ16C1DD1-G3-08
VMMBZ16C1DD1	H	G	3	-08	VMMBZ16C1DD1HG3-08

## PACKAGE DATA

DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VMMBZ16C1DD1	DFN1006-2B	2Y	0.83 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C
VMMBZ33C1DD1	DFN1006-2B	2N	0.83 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C

**ABSOLUTE MAXIMUM RATINGS** VMMBZ16C1DD1(T<sub>amb</sub> = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Acc. IEC 61000-4-5, 8/20 µs/single shot	I <sub>PPM</sub>	4	A
Peak pulse power	Acc. IEC 61000-4-5, 8/20 µs/single shot <sup>(1)</sup>	P <sub>PP</sub>	108	W
Peak pulse current	t <sub>p</sub> = 10/1000 µs <sup>(1)</sup>	I <sub>PPM</sub>	0.65	A
Peak pulse power	t <sub>p</sub> = 10/1000 µs <sup>(1)</sup>	P <sub>PP</sub>	15	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses <sup>(1)</sup>	V <sub>ESD</sub>	30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses <sup>(1)</sup>		30	kV
Operating temperature	Junction temperature	T <sub>J</sub>	-55 to +150	°C
Storage temperature		T <sub>stg</sub>	-55 to +150	°C

**ABSOLUTE MAXIMUM RATINGS** VMMBZ33C1DD1(T<sub>amb</sub> = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Acc. IEC 61000-4-5, 8/20 µs/single shot	I <sub>PPM</sub>	1.7	A
Peak pulse power	Acc. IEC 61000-4-5, 8/20 µs/single shot <sup>(1)</sup>	P <sub>PP</sub>	100	W
Peak pulse current	t <sub>p</sub> = 10/1000 µs <sup>(1)</sup>	I <sub>PPM</sub>	0.3	A
Peak pulse power	t <sub>p</sub> = 10/1000 µs <sup>(1)</sup>	P <sub>PP</sub>	15	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses <sup>(1)</sup>	V <sub>ESD</sub>	15	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses <sup>(1)</sup>		15	kV
Operating temperature	Junction temperature	T <sub>J</sub>	-55 to +150	°C
Storage temperature		T <sub>stg</sub>	-55 to +150	°C

**ELECTRICAL CHARACTERISTICS** VMMBZ16C1DD1(T<sub>amb</sub> = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS / REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	V <sub>RWM</sub>	-	-	14	V
Reverse voltage	At I <sub>R</sub> = 0.01 µA	V <sub>R</sub>	14	-	-	V
Reverse current	At V <sub>R</sub> = 14 V	I <sub>R</sub>	-	< 0.001	0.01	µA
	At V <sub>R</sub> = 14 V; T <sub>J</sub> = 150 °C <sup>(1)</sup>		-	0.06	10	µA
Reverse breakdown voltage	At I <sub>R</sub> = 1 mA	V <sub>BR</sub>	16.2	16.7	17.3	V
	At I <sub>R</sub> = 1 mA; T <sub>J</sub> = -40 °C to +150 °C <sup>(1)</sup>		15	-	18.7	V
Reverse clamping voltage	At I <sub>PP</sub> = I <sub>PPM</sub> = 4 A, t <sub>p</sub> = 8/20 µs	V <sub>C</sub>	20	23.7	27	V
	t <sub>p</sub> = 100 ns (TLP); I <sub>TLP</sub> = 16 A <sup>(1)</sup>	V <sub>C,TLP</sub>	-	26	-	V
Dynamic resistance	t <sub>p</sub> = 100 ns (TLP) <sup>(1)</sup>	r <sub>dyn</sub>	-	0.55	-	Ω
Capacitance	At V <sub>R</sub> = 0 V; f = 1 MHz	C <sub>D</sub>	12	14.5	17	pF

**ELECTRICAL CHARACTERISTICS** VMMBZ33C1DD1(T<sub>amb</sub> = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS / REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	V <sub>RWM</sub>	-	-	28	V
Reverse voltage	At I <sub>R</sub> = 0.01 µA	V <sub>R</sub>	28	-	-	V
Reverse current	At V <sub>R</sub> = 28 V	I <sub>R</sub>	-	< 0.001	0.01	µA
	At V <sub>R</sub> = 28 V; T <sub>J</sub> = 150 °C <sup>(1)</sup>		-	0.1	10	µA
Reverse breakdown voltage	At I <sub>R</sub> = 1 mA	V <sub>BR</sub>	32.7	33.7	34.8	V
	At I <sub>R</sub> = 1 mA; T <sub>J</sub> = -40 °C to +150 °C <sup>(1)</sup>		30	-	39.7	V
Reverse clamping voltage	At I <sub>PP</sub> = I <sub>PPM</sub> = 1.7 A, t <sub>p</sub> = 8/20 µs	V <sub>C</sub>	40	49	59	V
	t <sub>p</sub> = 100 ns (TLP); I <sub>TLP</sub> = 16 A <sup>(1)</sup>	V <sub>C,TLP</sub>	-	88	-	V
Dynamic resistance	t <sub>p</sub> = 100 ns (TLP) <sup>(1)</sup>	r <sub>dyn</sub>	-	3.3	-	Ω
Capacitance	At V <sub>R</sub> = 0 V; f = 1 MHz	C <sub>D</sub>	6	8	10	pF

**Note**<sup>(1)</sup> Guaranteed by design. Tested during device characterization

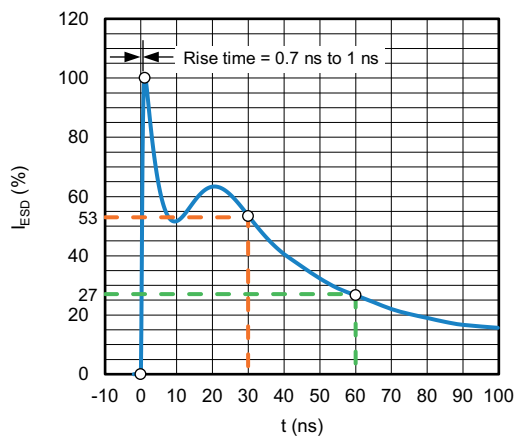


Fig. 1 - ESD Discharge Current Wave Form Acc. IEC 61000-4-2 (330  $\Omega$  / 150 pF)

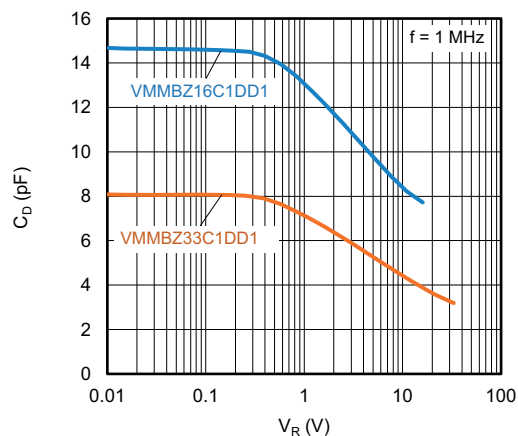


Fig. 4 - Typical Capacitance vs. Reverse Voltage

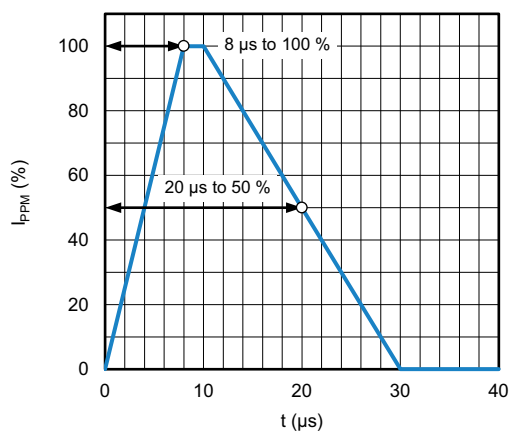


Fig. 2 - 8/20  $\mu$ s Peak Pulse Current Wave Form Acc. IEC 61000-4-5

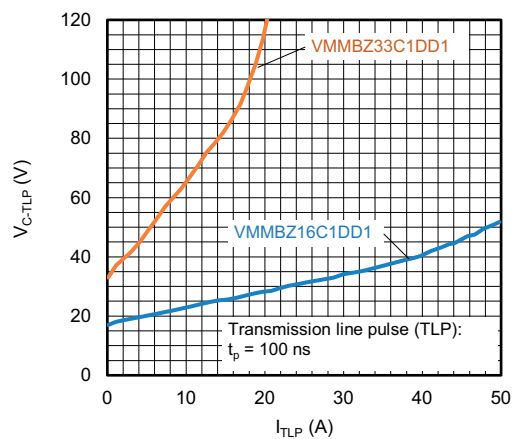


Fig. 5 - Typical Clamping Voltage vs. Peak Pulse Current

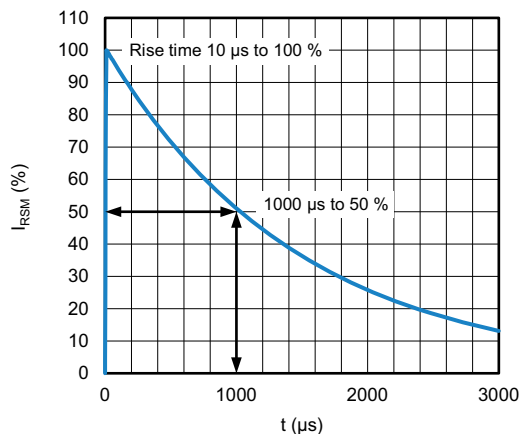


Fig. 3 - 10/1000  $\mu$ s Peak Pulse Current Wave Form

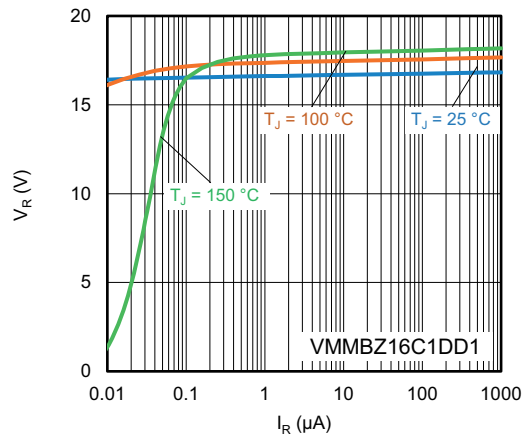


Fig. 6 - Typical Reverse Voltage vs. Reverse Current

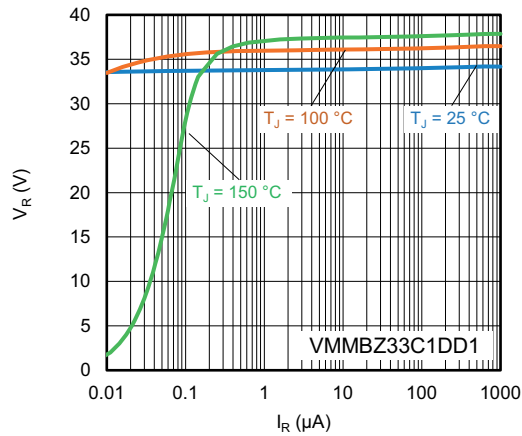


Fig. 7 - Typical Reverse Voltage vs. Reverse Current

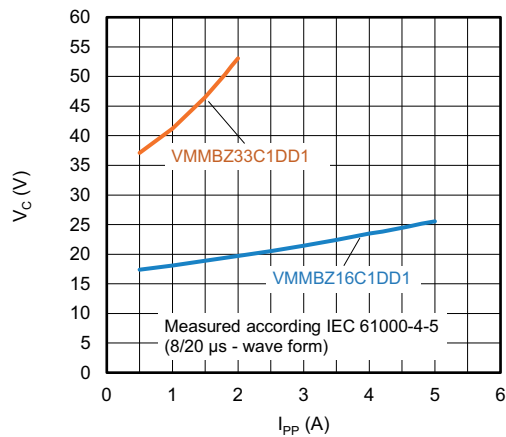


Fig. 8 - Typical Peak Clamping Voltage vs. Peak Pulse Current

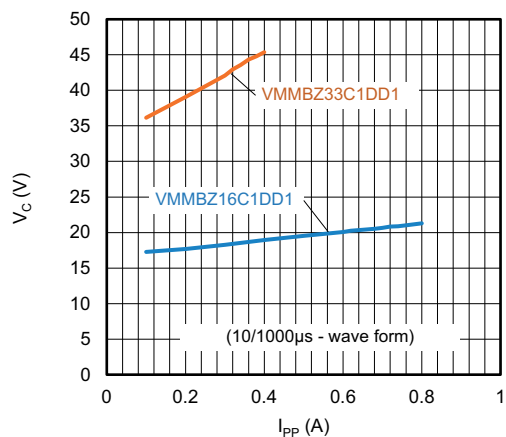
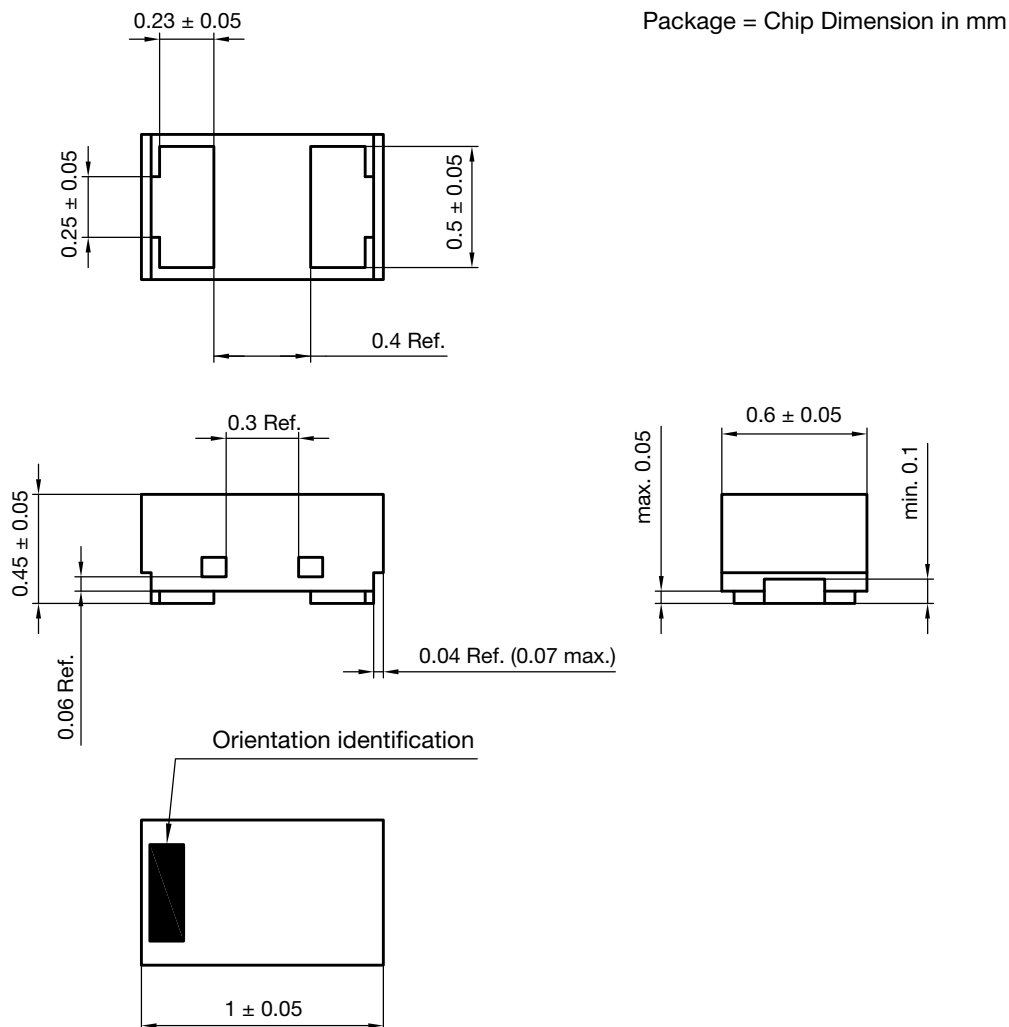


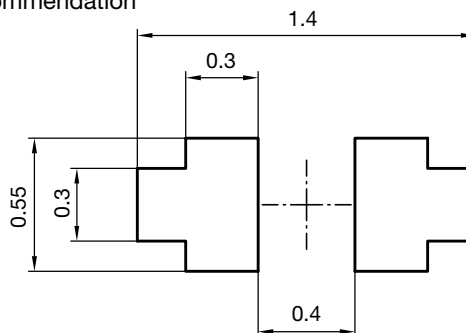
Fig. 9 - Typical Peak Clamping Voltage vs. Peak Pulse Current



## PACKAGE DIMENSIONS in millimeters (inches): DFN1006-2B



## Footprint recommendation

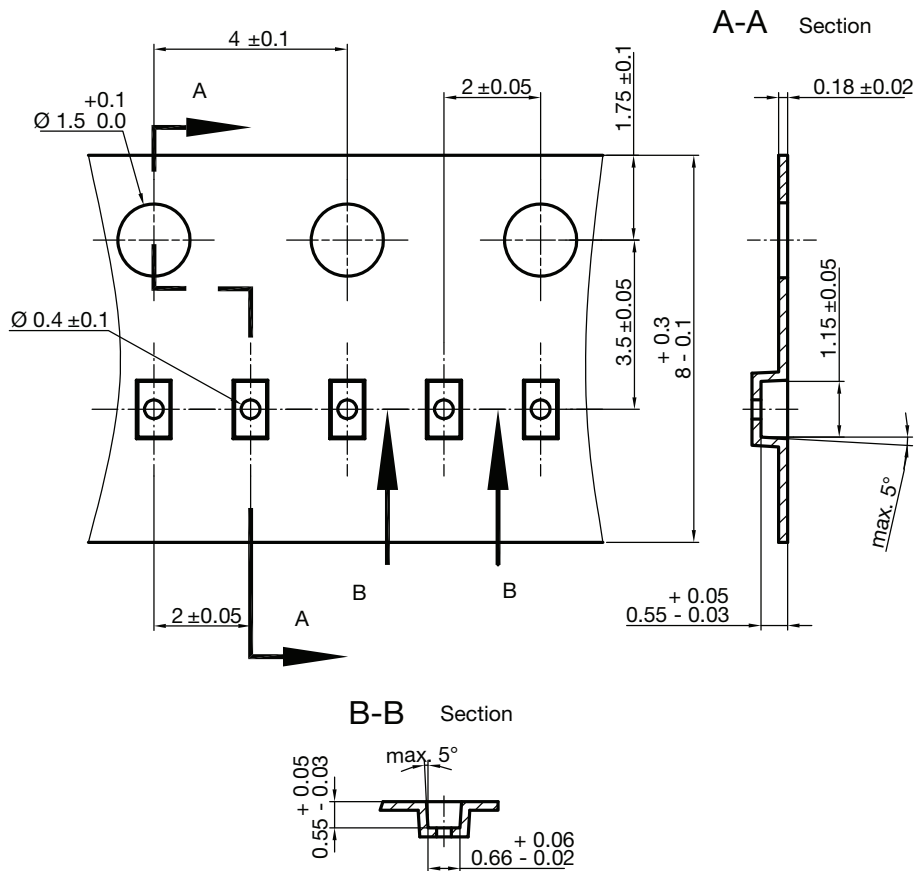


Document no.: S8-V-3906.04-059 (4)  
Created - Date: 11-Jul-2018  
Rev.5 - Date: 17-Sep-2021

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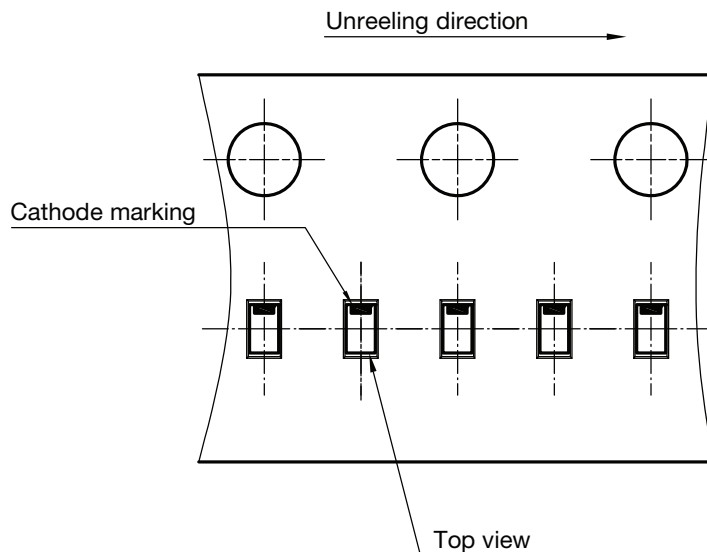
## CARRIER TAPE DFN1006-2B



S8-V-3906.04-063 (4)  
created 28.10.2019

surface resistance:  $10^5 - 10^{11} \frac{\text{OHMS}}{\text{SQ}}$   
Cumulative tolerances of 10 sprocket holes is  $\pm 0.2 \text{ mm}$

## ORIENTATION IN CARRIER TAPE DFN1006-2B



S8-V-3906.04-064 (4)  
created 28.10.2019



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